IN THE CLAIMS

The following is the complete listing of claims:

- 1. (Currently amended) A method of cleaning a chamber of an electron beam treatment apparatus, the method comprising:
- (a) generating an electron beam current though a cleaning gas to energize the cleaning gas in the chamber of the electron beam treatment apparatus;
 - (b) monitoring an electron beam current;
- (c) adjusting a pressure of the cleaning gas to maintain the electron beam current at a substantially constant value; and
- (d) stopping the flow of cleaning gas when the cleaning gas pressure becomes substantially constant for a predetermined length of time.

2-3. (Canceled)

- 4. (Original) The method of claim 1 wherein the cleaning gas comprises an oxygen-based gas.
- 5. (Original) The method of claim 4 wherein the oxygen-based gas comprises one or more of O_2 , ozone, NO, and H_2O .
- 6. (Original) The method of claim 1 wherein the cleaning gas comprises a fluorine-based gas.
- 7. (Previously presented) The method of claim 6 wherein the fluorine-based gas comprises one or more of NF₃, F₂, CF₄, C₂F₆, C₃F₈ and SF₆.

- 8. (Currently amended) A method of cleaning an electron beam treatment chamber, the method comprising:
- (a) generating an electron beam current though a cleaning gas to energize the cleaning gas in the electron beam treatment chamber; and
- (b) adjusting a pressure of the cleaning gas to maintain the electron beam current at a substantially constant value; and
- (c) stopping the flow of cleaning gas after the cleaning gas pressure becomes substantially constant for a predetermined length of time.
- 9. (Original) The method of claim 8 wherein the cleaning gas comprises an oxygen-based gas.
- 10. (Original) The method of claim 9 wherein the oxygen-based gas comprises one or more of O₂, ozone, NO, and H₂O.
- 11. (Original) The method of claim 8 wherein the cleaning gas comprises a fluorine-based gas.
- 12. (Previously presented) The method of claim 11 wherein the fluorine-based gas comprises one or more of NF₃, F₂, CF₄, C₂F₆, C₃F₈ and SF₆.
- 13. (Original) The method of claim 8 wherein a gas pressure of about1 Torr or greater is maintained in the chamber.
- 14. (Original) The method of claim 9 wherein a gas pressure of about1 Torr or greater is maintained in the chamber.
- 15. (Original) The method of claim 11 wherein a gas pressure of about1 Torr or greater is maintained in the chamber.

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- 16. (Currently amended) A method of cleaning a chamber of an electron beam treatment apparatus, the method comprising:
 - (a) introducing a cleaning gas into the chamber;
- (b) generating an electron beam current though the cleaning gas to energize the cleaning gas in the chamber;
- (c) setting in the chamber, an electron beam current of about 1 mA or above;
- (d) adjusting a pressure of the cleaning gas to maintain the electron beam current at a substantially constant value; and
- (e) determining an endpoint of the cleaning process and stopping introduction of the cleaning gas when the cleaning gas pressure reaches a substantially constant value and maintains the value for a length of time of 5 seconds.
- 17. (Previously presented) The method of claim 16 wherein the cleaning gas comprises an oxygen-based gas.
- 18. (Previously presented) The method of claim 17 wherein the oxygen-based gas comprises one or more of O₂, ozone, NO, and H₂O.
- 19. (Previously presented) The method of claim 16 wherein the cleaning gas comprises a fluorine-based gas.
- 20. (Previously presented) The method of claim 19 wherein the fluorine-based gas comprises one or more of NF₃, F₂, CF₄, C₂F₆, C₃F₈ and, SF₆.
- 21. (Previously presented) The method of claim 1 comprising stopping the flow of cleaning gas when the cleaning gas pressure becomes substantially constant for a length of time of 5 seconds.

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- 22. (Previously presented) The method of claim 8 comprising stopping the flow of cleaning gas when the cleaning gas pressure becomes substantially constant for a length of time of 5 seconds.
- 23. (Previously presented) The method of claim 16 comprising setting in the chamber, an electron beam current of about 10 mA or above.